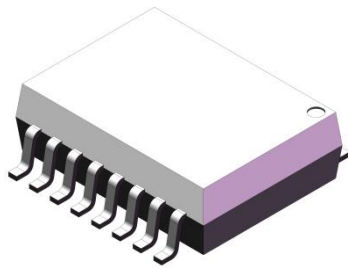
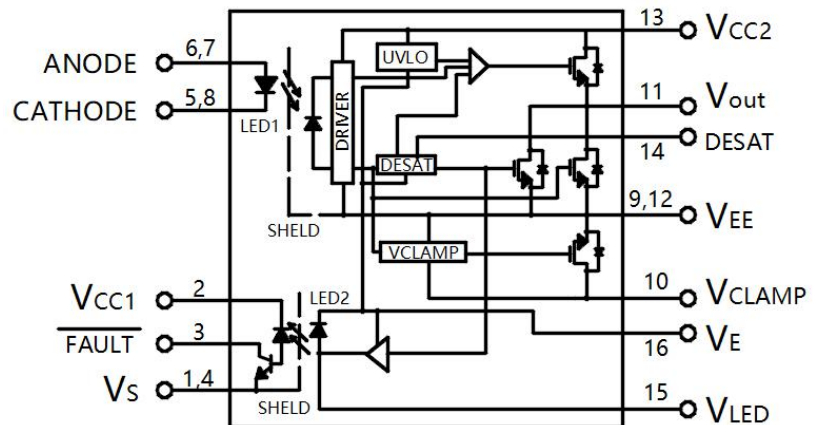


## XL332J

### Product packaging logic diagram



WSOP16



Pin Configuration

### Features

- 50 kV/ $\mu$ s minimum Common Mode Rejection
- 15V ~ 30V Wide operating VCC Range
- Maximum peak output current 2.5A
- The output stage can drive IGBTs with 150A and 1200V;
- Creepage distance > 7.0mm;
- Operating Temperature: -55°C~110°C
- Environmentally friendly products, compliant with CQC, UL, and VDE requirements

### Mechanical Data

- Case: WSOP16
- Molding Compound: UL Flammability Classification Rating 94V-0
- Terminals: Matte tin-plated leads; solder ability-per MIL-STD-202, Method 208

### Applications

- Industrial Automation Equipment: Used for inverters and AC servo drives to improve system stability and energy efficiency.
- Automotive Electronic Systems: Applied in motor drives and electronic braking systems for electric vehicles, enhancing safety and switching efficiency.
- New Energy Generation: Optimizes the process of energy conversion and transmission in photovoltaic (PV) and wind power generation applications.
- Power Transmission Systems: Supports High-Voltage Direct Current (HVDC) and Flexible AC Transmission Systems (FACTS), ensuring the stable operation of transmission lines.



### XL332J

### Ordering Information

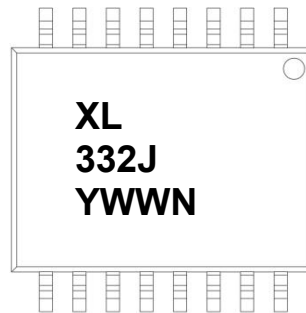
XL     332J     (M)     (G)     -     (U)     (N)     (Y)  
 ①        ②        ③        ④               ⑤        ⑥        ⑦

- ① Brand(XL)
- ② Product series( 332J )
- ③ Package type ( WSOP16 )
- ④ Halogen option(None :Halogen free)
- ⑤ Lead frame (None: Copper)
- ⑥ Customer option 1 (0-9 or A-Z or none)
- ⑦ Customer option 2 (0-9 or A-Z or none)

Part Number	Package	Shipping Quantity	Marking Code
XL332JSX	WSOP16	1000pcs / Tape & Reel	XL3120X

### Marking Information

- " XL" denotes brand.
- " 332J " denotes Product series.
- " Y" denotes Year : A(2024), B(2025), C(2026)
- " WW" denotes Week' s number .
- " N" denotes the day of Week.



**Pin Function Description**

1	Vs	VE	16
2	Vcc1	VLED	15
3	$\overline{\text{FAULT}}$	DESAT	14
4	Vs	Vcc2	13
5	CATHODE	VEE	12
6	ANODE	VOUT	11
7	ANODE	VCLAMP	10
8	CATHODE	VEE	9

PIN	Symbol	Description
1	VS	Input Ground
2	VCC1	Positive input supply voltage (3.3V to 5.5V)
3	$\overline{\text{FAULT}}$	Fault output. FAULT changes from a high impedance State to a logic low output within 5 $\mu$ s of the voltage on The DESAT pin exceeding an internal reference voltage of 7V. FAULT output is an open collector which allows the FAULT outputs from all AT332J in a circuit to be connected together in a “wired OR” forming a single fault bus for inter facing directly to the micro-controller.
4	VS	Input Ground
5	CATHODE	Cathode
6	ANODE	Anode
7	ANODE	Anode
8	CATHODE	Cathode
9	VEE	Output supply voltage.
10	VCLAMP	Miller clamp
11	VOUT	Gate drive voltage output
12	VEE	Output supply voltage.
13	VCC2	Positive output supply voltage
14	DESAT	Desaturation voltage input. When the voltage on DESAT exceeds an internal reference voltage of 6.5V while the IGBT is on, FAULT output is changed from a high impedance state to a logic low state within 5 $\mu$ s.
15	VLED	LED anode. This pin must be left unconnected for guaranteed data sheet performance. (For optical coupling testing only)
16	VE	Common (IGBT emitter) output supply voltage.

## XL332J

### Maximum Ratings (@ T<sub>A</sub> = 25°C unless otherwise specified)

Parameter		Symbol	Min.	Max.	Unit
Input	Average Input Current	IF(AVG)	25	-	mA
	Peak Transient Input Current	IF(TRAN)	1.0	-	A
	Reverse Input Voltage	VR	5	-	V
	Positive Input Supply Voltage	VCC1	-0.5	7.0	V
	Input IC Power Dissipation	PI	150	-	mW
Output	"High" Peak Output Current	OH(PEAK)	-	2.5	A
	"Low" Peak Output Current	IOL(PEAK)	-	2.5	A
	FAULT Output Current	IFFAULT	-	8.0	mA
	FAULT Pin Voltage	VFAULT	-0.5	VCC1	V
	Total Output Supply Voltage	(VCC2 - VEE)	-0.5	35	V
	Negative Output Supply Voltage	(VE - VEE)	-0.5	15	V
	Positive Output Supply Voltage	(VCC2 - VE)	-0.5	30	V
	Gate Drive Output Voltage	VO(PEAK)	-0.5	VCC2	V
	Peak Clamping Sinking Current	IClamp	-	1.7	A
	Miller Clamping Pin Voltage	VClamp	-0.5	VCC2	V
	DESAT Voltage	VDESAT	VE	VE + 10	V
	Output IC Power Dissipation	PO	0	600	mW

### Thermal Characteristics

Parameter	Symbol	Value	Unit
Isolation Voltage *1	VISO	5000	Vrms
Operating Temperature	TOPR	-55 ~ +100	°C
Storage Temperature Range	TSTG	-55 ~ +125	°C
Soldering Temperature *2	TSOL	260	°C

Notes:

1. 40 to 60% RH, AC for 1 minute
2. For 10 seconds

## XL332J

### Electrical Characteristics (@ T<sub>A</sub> = 25°C unless otherwise specified)

Parameter	Symbol	Condition	Min.	Typ.	Max.	Unit
FAULT Logic Low Output Voltage	VFAULTL	IFault = 1.1mA, VCC1 = 5.5V	-	0.07	0.4	V
		IFault = 1.1mA, VCC1 = 3.3V	-	0.07	0.4	V
FAULT Logic High Output Current	IFaultH	VFAULT = 5.5V, VCC1 = 5.5V	-	0.05	0.5	μA
		VFAULT = 3.3 V, VCC1 = 3.3V	-	0.01	0.3	μA
High Level Output Current	IOH	VO = VCC2 - 4	-0.5	-1.5	-	A
		VO = VCC2 -15	-2.0	-	-	A
Low Level Output Current	IOL	VO = VEE + 2.5	0.5	1.5	-	A
		VO = VEE + 15	2.0	-	-	A
Low Level Output Current During Fault Condition	IOLF	VOUT - VEE = 14V	90	140	230	mA
High Level Output Voltage	VOH	O = -650μA	VCC-2.9	VCC-0.1	-	V
Low Level Output Voltage	VOL	IO = 100mA	-	0.08	0.5	V
Clamp Pin Threshold Voltage	Vt Clamp	-	-	-	2.5	V
Clamp Low Level Sinking Current	ICL	VO = VEE + 2.5	0.5	1.5	-	A
High Level Supply Current	ICC2H	IO = 0mA	-	2.4	4.5	mA
Low Level Supply Current	ICC2L	IO = 0mA	-	2.4	4.5	mA
Blanking Capacitor Charging Current	CHG	VDESAT = 2V	-0.13	-0.23	-0.33	mA
Blanking Capacitor Discharge Current	IDSCHG	VDESAT = 7.0V	10	30	-	mA
DESAT Threshold	VDESAT	VCC2 -VE >VUVLO	6	6.6	7.5	V
UVLO Threshold	VUVLO+	IF = 10mA, VO > 5 V	10.5	11.6	12.5	V
	VUVLO-	IF = 10mA, VO < 5 V	9.2	10.5	11.1	V
UVLO Hysteresis	(VUVLO+ VUVLO-)	-	-	1.2	-	V
Threshold Input Current Low to High	IFLH	IO = 0mA, VO > 5 V	-	2.6	5.0	mA
Threshold Input Voltage High to Low	VFHL	IO = 0mA, VO < 5 V	0.8	-	-	V
Input Forward Voltage	VF	IF = 10mA	1.2	1.4	1.95	V
Temperature Coefficient of Input Forward Voltage	ΔVF/ΔTA	-	-	-1.3	-	mV/°C
Input Reverse Breakdown Voltage	BVR	IR = 10uA	5	-	-	V
Input Capacitance	CIN	f = 1MHz, VF = 0V	-	70	-	pF

## XL332J

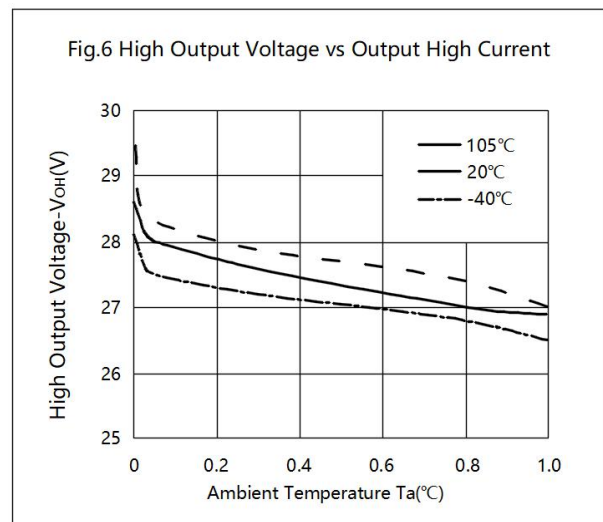
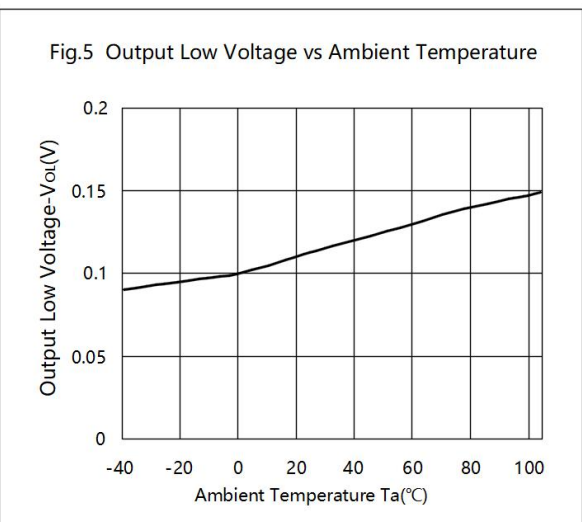
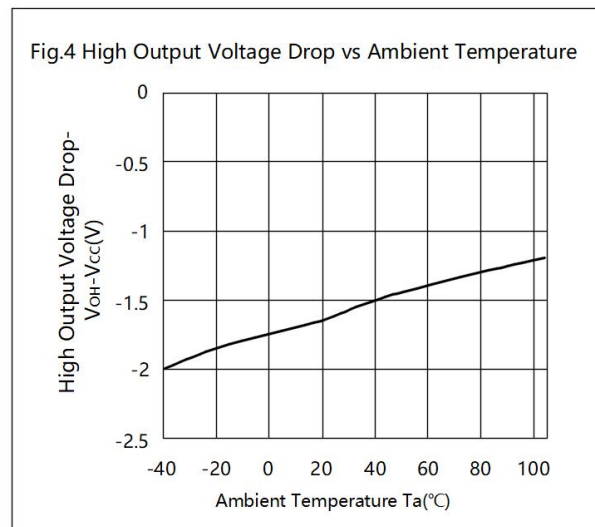
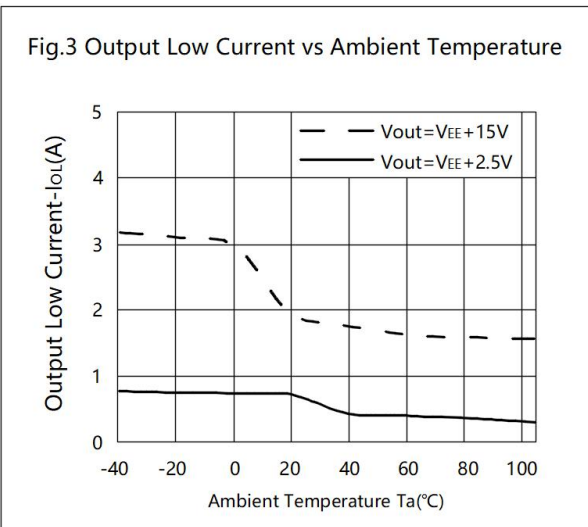
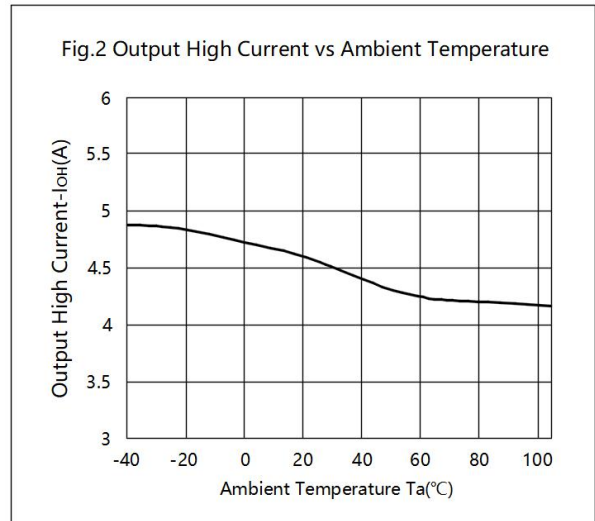
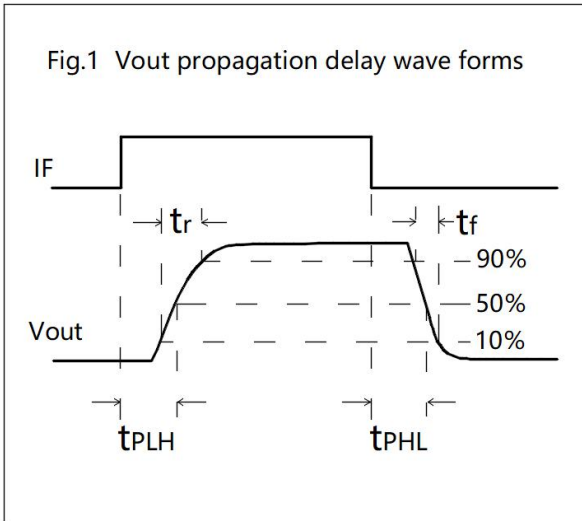
### Switching Characteristics (@ $T_A = -40^{\circ}\text{C} \sim 85^{\circ}\text{C}$ , $V_{CC} = 5\text{V}$ , $I_F = 7.5\text{mA}$ , unless otherwise specified)

Unless otherwise noted, all typical values at  $T_A = 25^{\circ}\text{C}$ ,  $V_{CC2} = 30\text{V}$ ,  $V_{EE} = \text{Ground}$ ; All Minimum/Maximum specifications are at Recommended Operating Conditions.

Parameter	Symbol	Condition	Min.	Typ.	Max.	Unit
Propagation Delay Time to High Output Level	tPLH	$R_g = 10\ \Omega$ , $C_g = 10\text{nF}$ , $f = 10\text{kHz}$ , Duty Cycle = 50%, $I_F = 10\text{mA}$ , $V_{CC2} = 30\text{V}$	50	180	250	ns
Propagation Delay Time to Low Output Level	tPHL		50	180	250	ns
Pulse Width Distortion	PWD		-80	30	80	ns
Propagation Delay Difference Between Any Two Parts or Channels	PDD		-100	-	100	ns
Rise Time	Tr		-	50	-	ns
Fall Time	Tf		-	50	-	ns
DESAT Sense to 90% VO Delay	tDESAT (90%)	$C_{DESAT} = 100\text{pF}$ , $R_g = 10\ \Omega$ , $C_g = 10\text{nF}$ , $V_{CC2} = 30\text{V}$	-	0.25	0.5	$\mu\text{s}$
DESAT Sense to 10% VO Delay	tDESAT (10%)		-	2	3	$\mu\text{s}$
DESAT Sense to Low Level FAULT Signal Delay	tDESAT (FAULT)	$C_{DESAT} = 100\text{pF}$ , $R_F = 2.1\text{k}\Omega$ , $C_F = \text{Open}$ , $R_g = 10\ \Omega$ , $C_g = 10\text{nF}$ , $V_{CC2} = 30\text{V}$	-	0.25	0.5	$\mu\text{s}$
DESAT Sense to DESAT Low Propagation Delay	tDESAT (LOW)		-	0.25	-	$\mu\text{s}$
DESAT Input Mute	tRESET (MUTE)	-	5	15	-	$\mu\text{s}$
RESET to High Level FAULT Signal Delay	tRESET (FAULT)	$C_{DESAT} = 100\text{pF}$ , $R_F = 2.1\text{k}\Omega$ , $R_g = 10\ \Omega$ , $C_g = 10\text{nF}$ , $V_{CC1} = 5.5\text{V}$ , $V_{CC2} = 30\text{V}$	-	1	2.0	$\mu\text{s}$

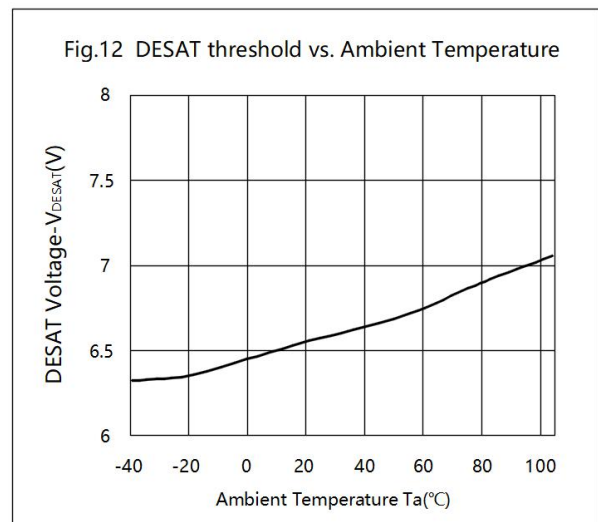
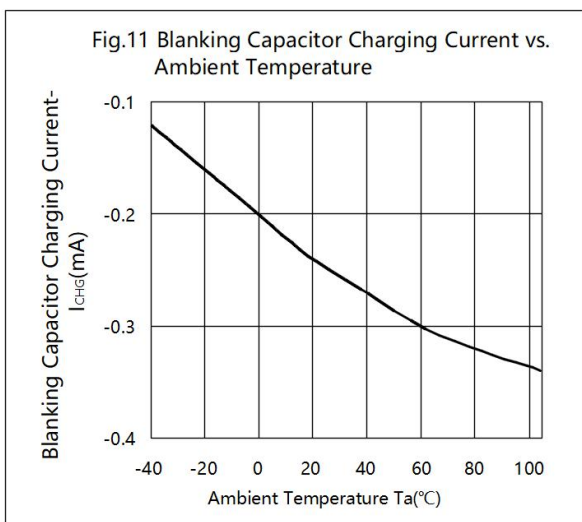
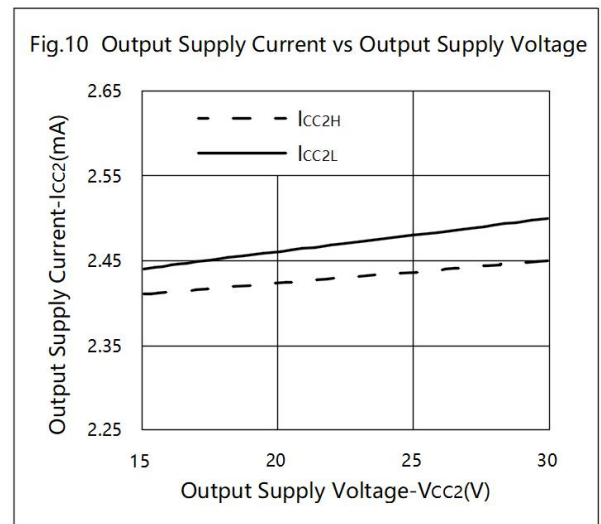
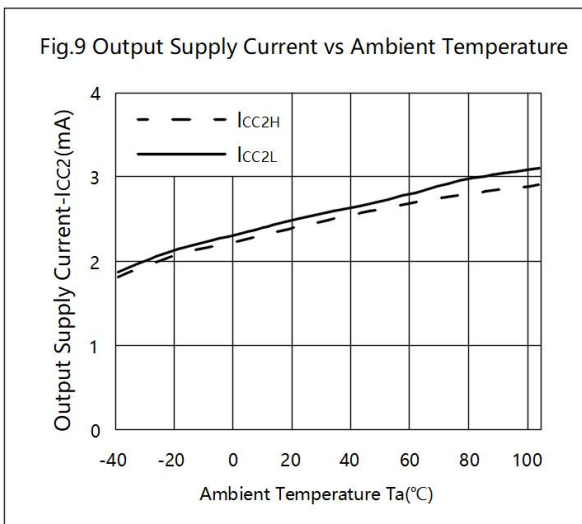
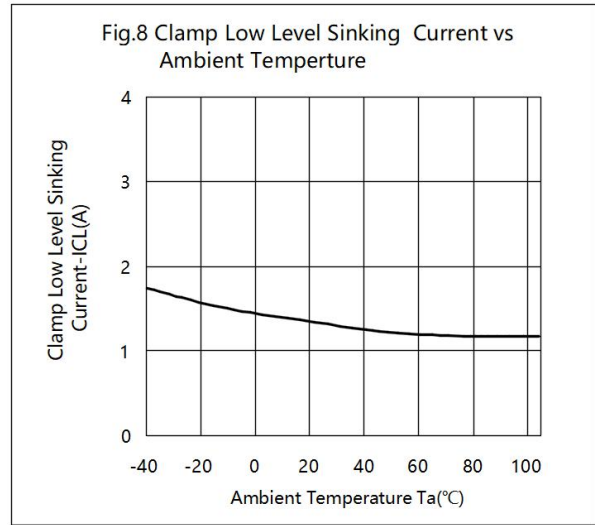
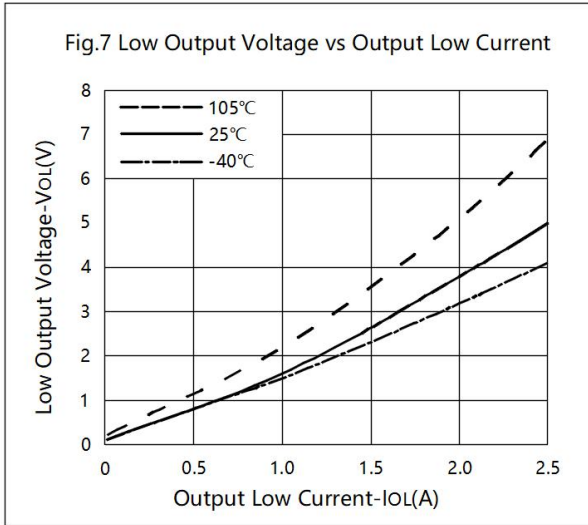
## XL332J

### Ratings and Characteristics Curves (@ $T_A = 25^\circ\text{C}$ unless otherwise specified)



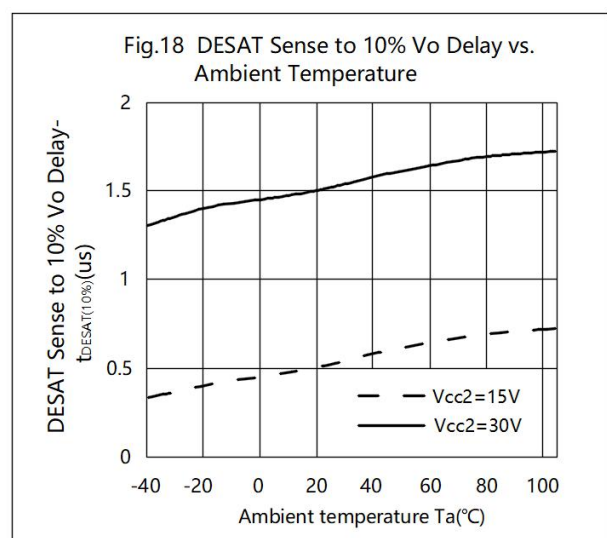
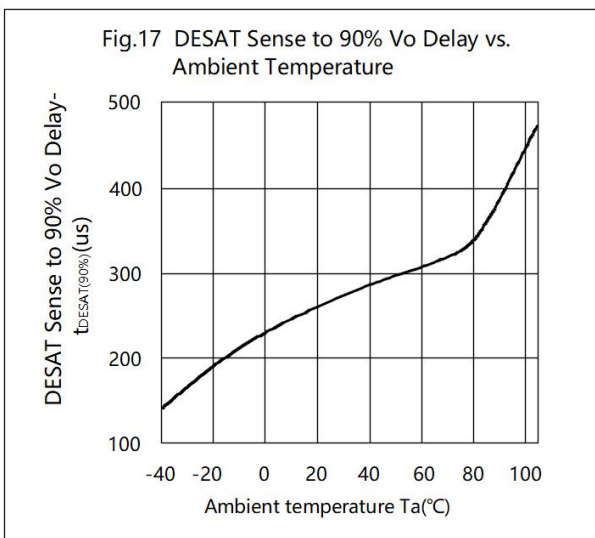
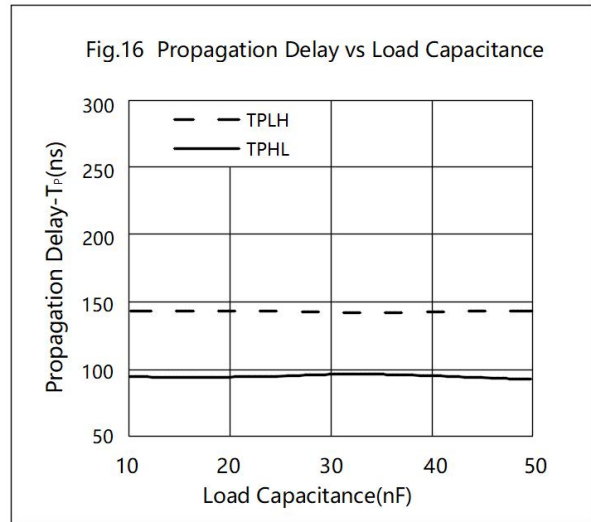
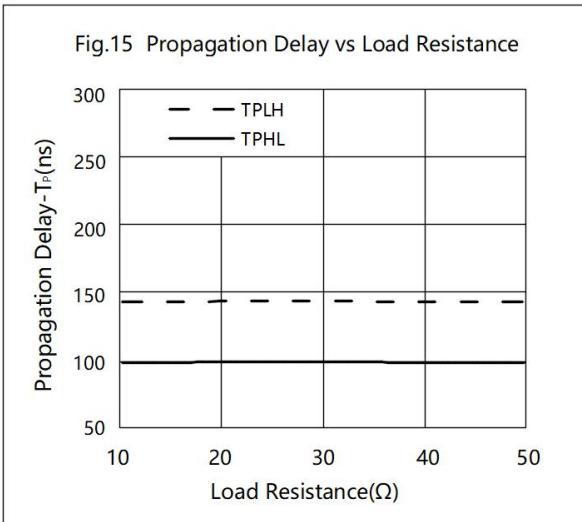
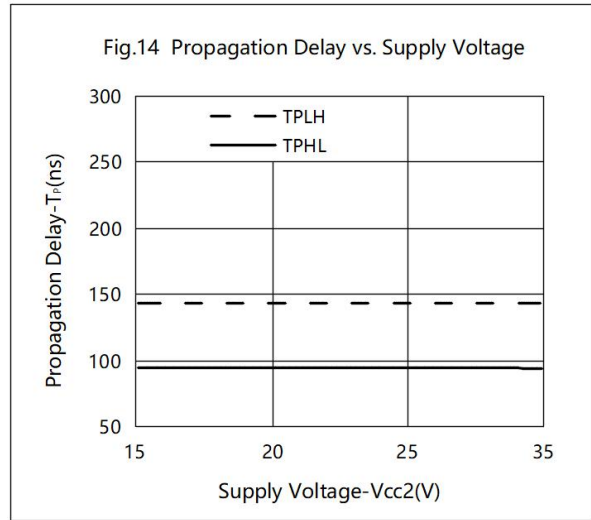
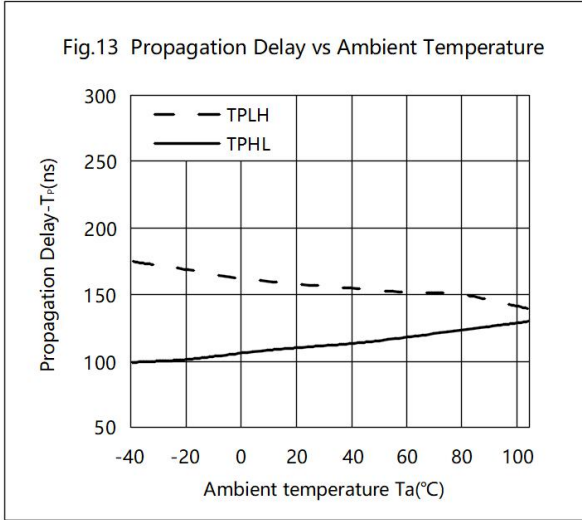
## XL332J

### Ratings and Characteristics Curves (@ $T_A = 25^\circ\text{C}$ unless otherwise specified)



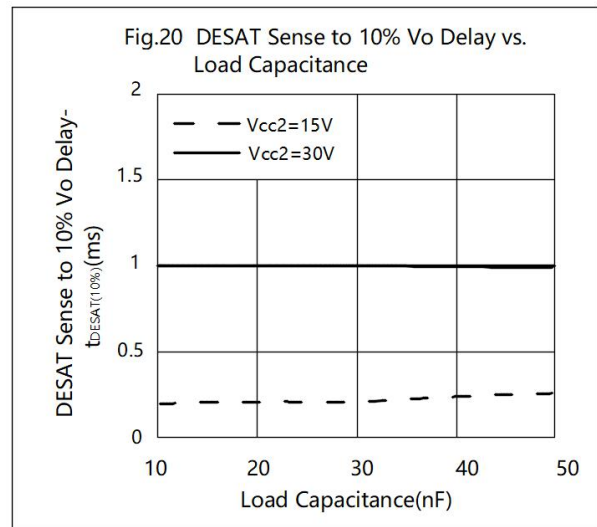
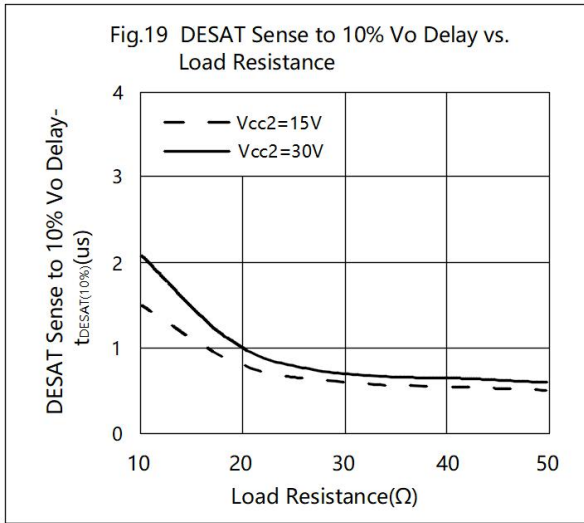
## XL332J

### Ratings and Characteristics Curves (@ $T_A = 25^\circ\text{C}$ unless otherwise specified)



## XL332J

### Ratings and Characteristics Curves (@ $T_A = 25^\circ\text{C}$ unless otherwise specified)



### Test Circuits Diagrams

Fig21.  $I_{\text{OH}}$  Pulsed Test Circuit

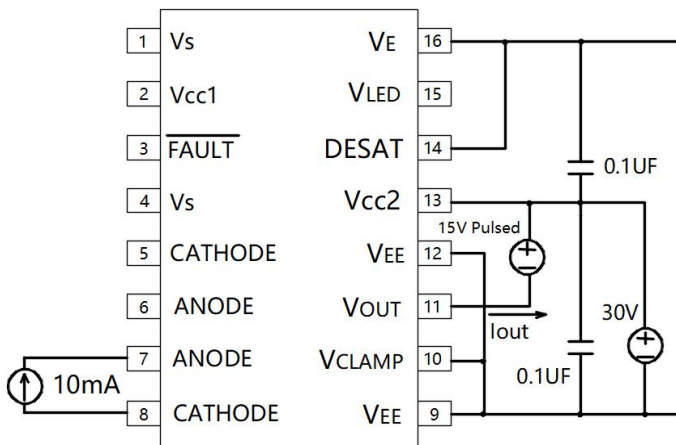


Fig22.  $I_{\text{OL}}$  Pulsed Test Circuit

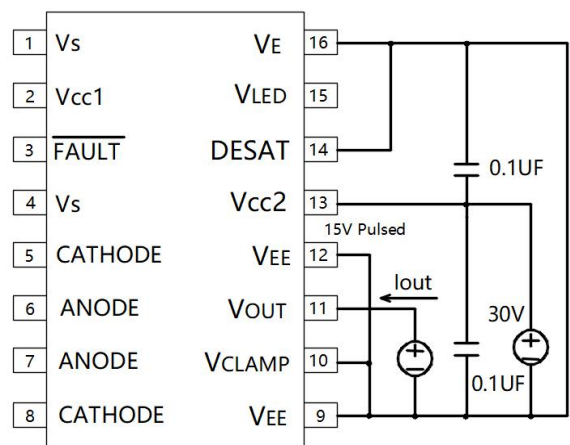


Fig23.  $V_{\text{OH}}$  Pulsed Test Circuit

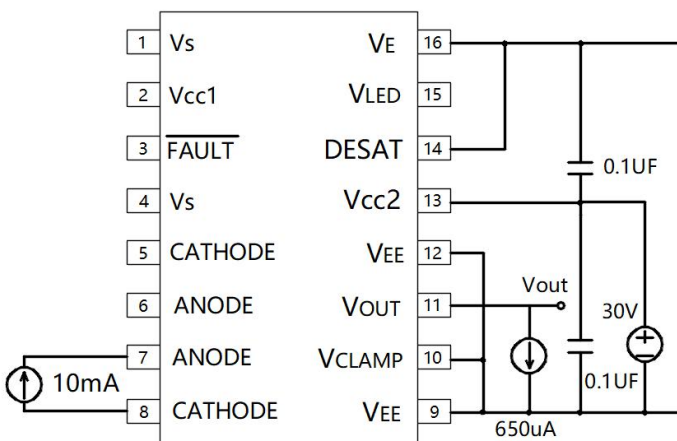
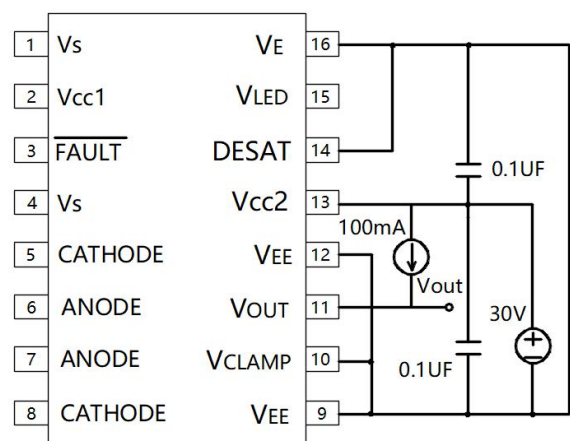


Fig24.  $V_{\text{OL}}$  Pulsed Test Circuit



### XL332J

Fig25.  $I_{CC2H}$  Test Circuit

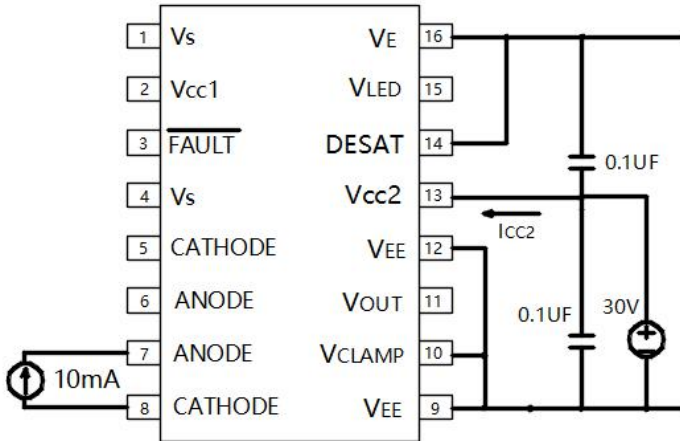


Fig26.  $I_{CC2L}$  Test Circuit

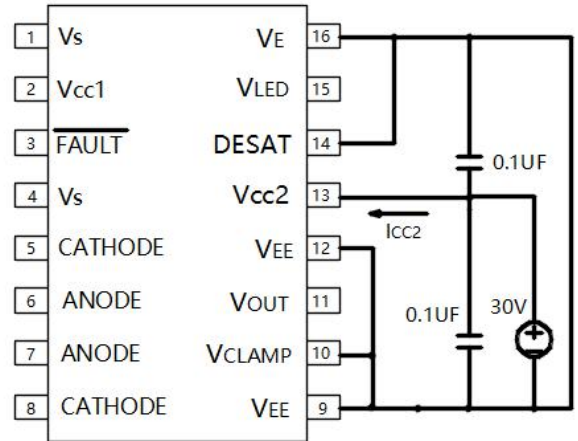


Fig27.  $I_{CC2H}$  Pulsed Test Circuit

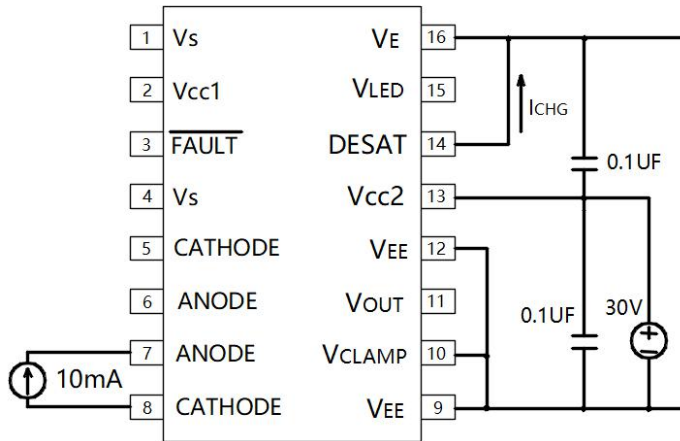


Fig28.  $I_{DSCHG}$  Test Circuit

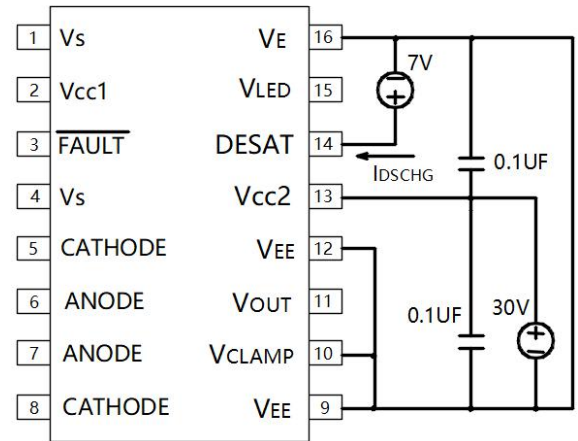


Fig29.  $T_{PLH}, T_{PHL}, T_r, T_f$  Test Circuit

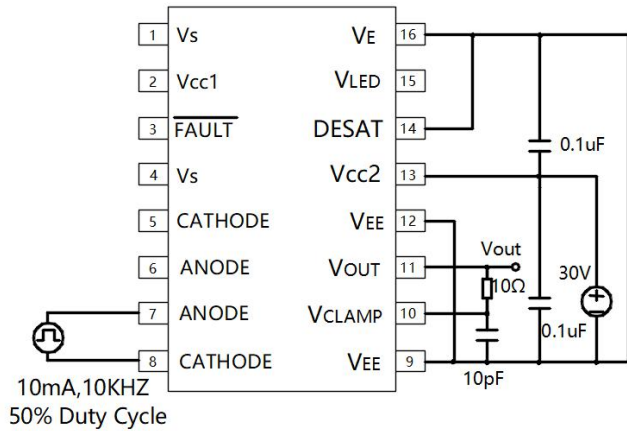
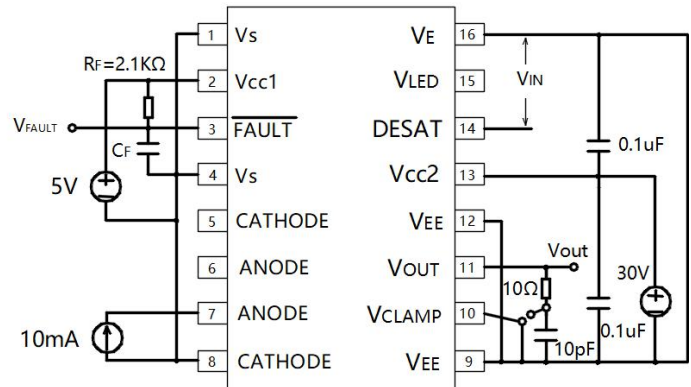


Fig30.  $T_{DESAT}$  Fault Test Circuit



**XL332J**

Fig31. CMR Test Circuit LED2 off

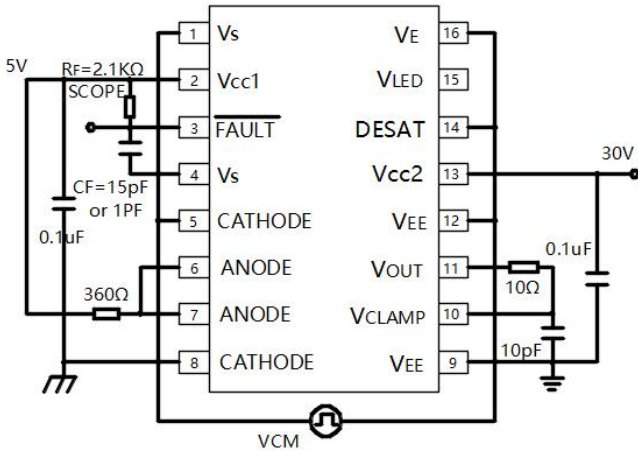


Fig32. CMR Test Circuit LED2 on

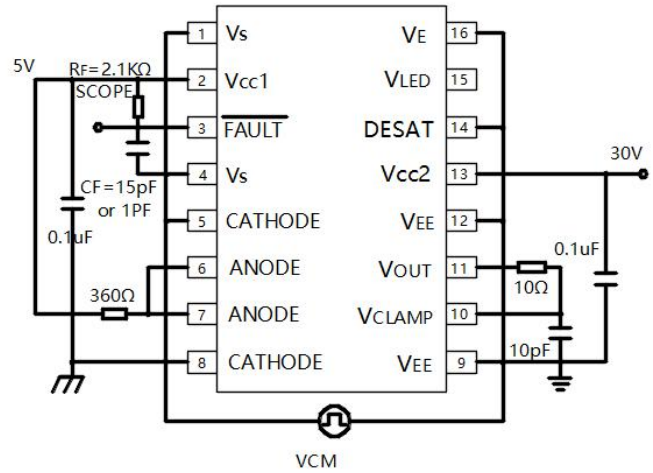


Fig33. CMR Test Circuit LED1 on

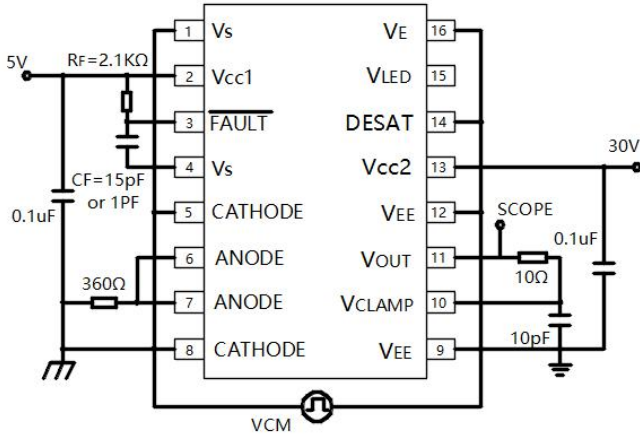
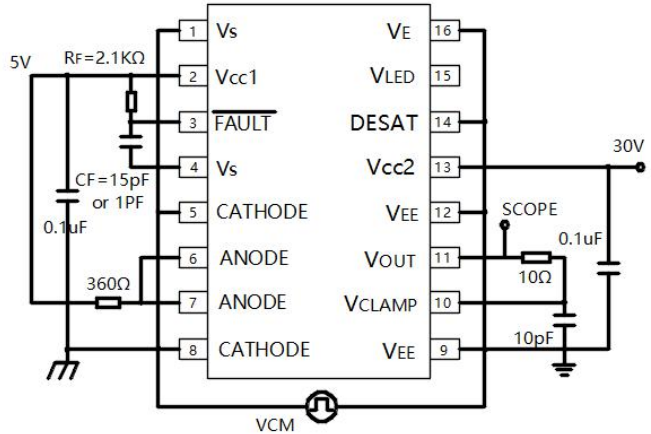


Fig34. CMR Test Circuit LED1 off



**Application Information**

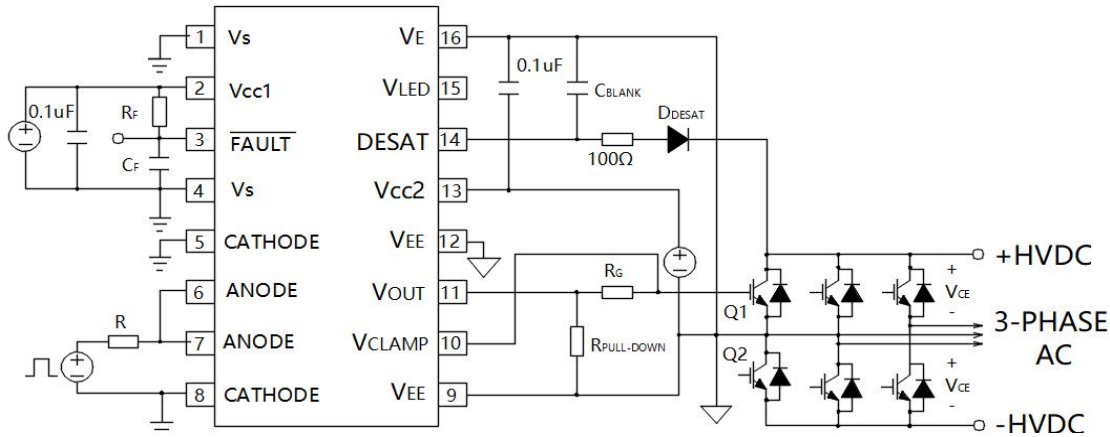
**1、 Product Overview Description**

The AT332J are highly integrated power control devices that incorporates all the necessary components for a complete, isolated IGBT / MOSFET gate drive circuit with fault protection and feedback into one SOP16 package. Active Miller clamp function eliminates the need of negative gate drive in most application application and allows the use of simple bootstrap supply for high side driver. An optically isolated power output stage drives IGBTs with power ratings of up to 150A and 1200V. A high speed internal optical link minimizes the propagation delays between he micro controller and the IGBT while allowing the two systems to operate at very large common mode voltage differences that are common in industrial motor drives and other power switching applications. An output IC provides local protection for the IGBT to prevent damage during over current, and a second opticalink provides a fully isolated fault status feedback signal for the micro controller. A built in "watchdog" circuit, UVLO monitors the power stage supply voltage to prevent IGBT caused by insufficient gate drive voltages. This integrated IGBT gate driver is designed to increase the performance and reliability of a motor drive without the cost, size, and complexity of a discrete design.



## XL332J

Fig35. Recommended application circuit (Single Supply)  
with desaturation detection and active Miller Clamp



## Description of Operation

### 1、 Normal Operation

During normal operation, VOUT of the AT332J is controlled by input LED current IF (pins 5, 6, 7 and 8), with the IGBT collector-to-emitter voltage being monitored through DESAT. The FAULT output is high. See Fig 36.

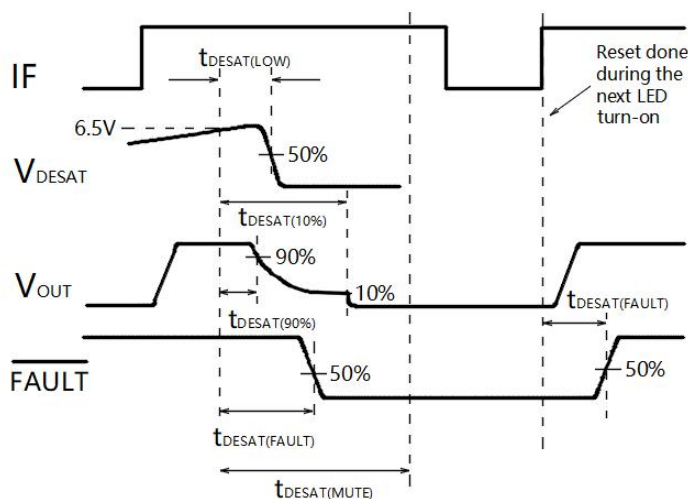
### 2、 Fault Condition

The DESAT pin monitors the IGBT Vce voltage. When the voltage on the DESAT pin exceeds 6.5V while the IGBT is on, VOUT is slowly brought low in order to “softly” turn-off the IGBT and prevent large di/dt induced voltages. Also activated is an internal feedback channel which brings the FAULT output low for the purpose of notifying the micro- controller of the fault condition.

### 3、 Fault Reset

Once fault is detected, the output will be muted for 5μs (minimum). All input LED signals will be ignored during the mute period to allow the driver to completely soft shut-down the IGBT. The fault mechanism can be reset by the next LED turn-on after the 5us (minimum) mute time. See Fig 36.

Fig 36. Fault Timing diagram



**4. Output Control**

The outputs (VOUT and FAULT) of the AT332J are controlled by the combination of IF, UVLO and a detected IGBT Desat condition. Once UVLO is not active ( $VCC2 - VE > VUVLO$ ), VOUT is allowed to go high, and the DESAT (Pin14) detection feature of the AT332J will be the primary source of IGBT protection. Once VCC2 is increased from 0V to above VUVLO+, DESAT will remain functional until VCC2 is decreased below VUVLO-. Thus, the DESAT detection and UVLO features of the AT332J work in conjunction to ensure constant IGBT protection.

IF	UVLO(VCC2-VE)	DESAT Function	FAULT Output	VOUT
ON	Active	Not Active	High	Low
ON	Not Active	Active (with DESAT fault)	Low (FAULT)	Low
ON	Not Active	Active (no DESAT fault)	High (or no fault)	High
OFF	Active	Not Active	High	Low
OFF	Not Active	Not Active	High	Low

**5. Desaturation Detection and High Current Protection**

The AT332J satisfies these criteria by combining a high speed, high output current driver, high voltage optical isolation between the input and output, local IGBT desaturation detection and shutdown, and an optically isolated fault status feedback signal into a single 16-pin surface mount package.

The fault detection method, which is adopted in the AT332J, is to monitor the saturation (collector) voltage of the IGBT and to trigger a local fault shutdown sequence if the collector voltage exceeds a predetermined threshold. A small gate discharge device slowly reduces the high short circuit IGBT current to prevent damaging voltage spikes. Before the dissipated energy can reach destructive levels, the IGBT is shut off. During the off state of the IGBT, the fault detect circuitry is simply disabled to prevent false 'fault' signals.

The alternative protection scheme of measuring IGBT current to prevent desaturation is effective if the short circuit capability of the power device is known, but this method will fail if the gate drive voltage decreases enough to only partially turn on the IGBT. By directly measuring the collector voltage, the AT332J limits the power dissipation in the IGBT even with insufficient gate drive voltage. Another more subtle advantage of the desaturation detection method is that power dissipation in the IGBT is monitored, while the current sense method relies on a preset current threshold to predict the safe limit of operation. Therefore, an overly conservative over current threshold is not needed to protect the IGBT.

**6. Slow IGBT Gate Discharge during Fault Condition**

When a desaturation fault is detected, a weak pull-down device in the AT332J output drive stage will turn on to 'softly' turn off the IGBT. This device slowly discharges the IGBT gate to prevent fast changes in drain current that could cause damaging voltage spikes due to lead and wire inductance.



**XL332J**

**Other Recommended Components**

The application circuit in Fig 35 includes an output pull-down resistor, a DESAT pin protection resistor, a FAULT pin capacitor, and a FAULT pin pullup resistor and Active Miller Clamp connection.

Figure 37. Output pull-down resistor

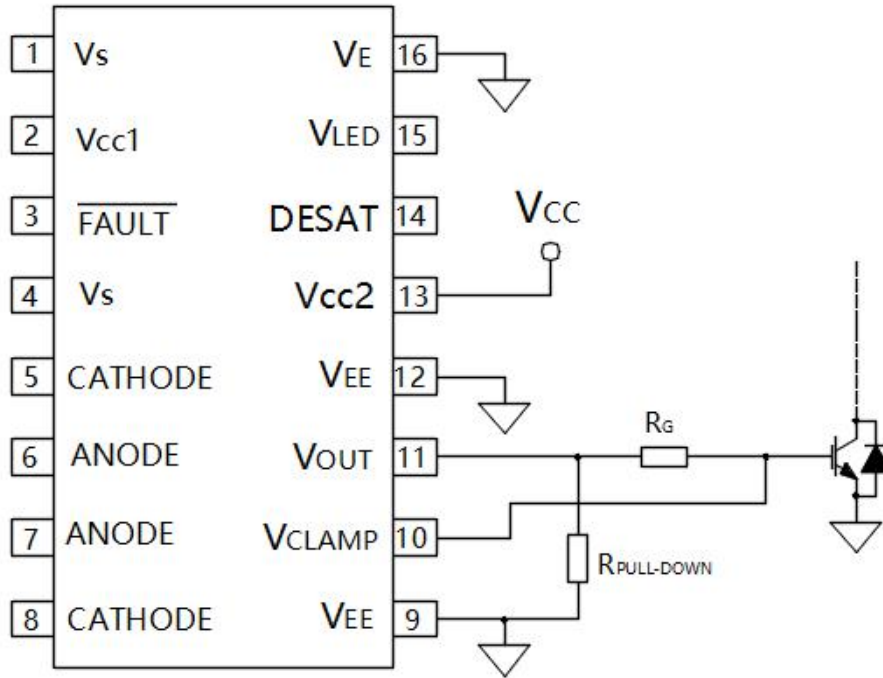
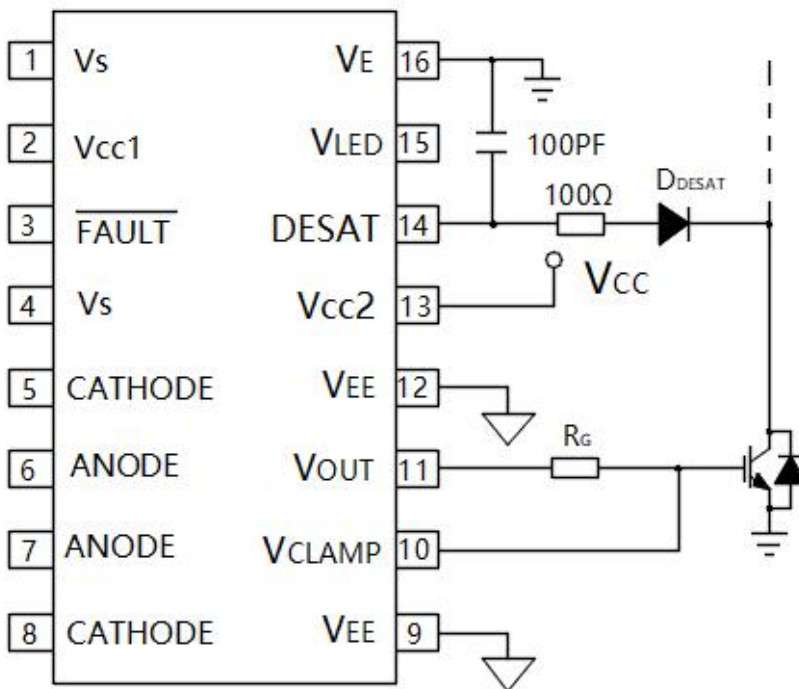


Figure 38. DESAT pin protection



## XL332J

### 1、 Output Pull-Down Resistor

During the output high transition, the output voltage rapidly rises to within 3 diode drops of VCC2 . If the output current then drops to zero due to a capacitive load, the output voltage will slowly rise from roughly VCC2-3(VBE) to VCC2 within a period of several microseconds. To limit the output voltage to VCC2-3(VBE), a pull-down resistor, RPULL-DOWN between the output and VEE is recommended to sink a static current of several 650µA while the output is high. Pull-down resistor values are dependent on the amount of positive supply and can be adjusted according to the formula,  $R_{pull-down} = [VCC2 - 3 * (VBE)] / 650\mu A$ .

### 2、 DESAT Pin Protection Resistor

The freewheeling of fly back diodes connected across the IGBTs can have large instantaneous forward voltage transients which greatly exceed the nominal forward voltage of the diode. This may result in a large negative voltage spike on the DESAT pin which will draw substantial current out of the driver if protection is not used. To limit this current to levels that will not damage the driver IC, a 100 ohm resistor should be inserted in series with the DESAT diode. The added resistance will not alter the DESAT threshold or the DESAT blanking time.

3、 Rapid common mode transients can affect the fault pin voltage while the fault output is in the high state. A 1000pF capacitor should be connected between the fault pin and ground to achieve adequate CMOS noise margins at the specified CMR value of 50kV/µs.

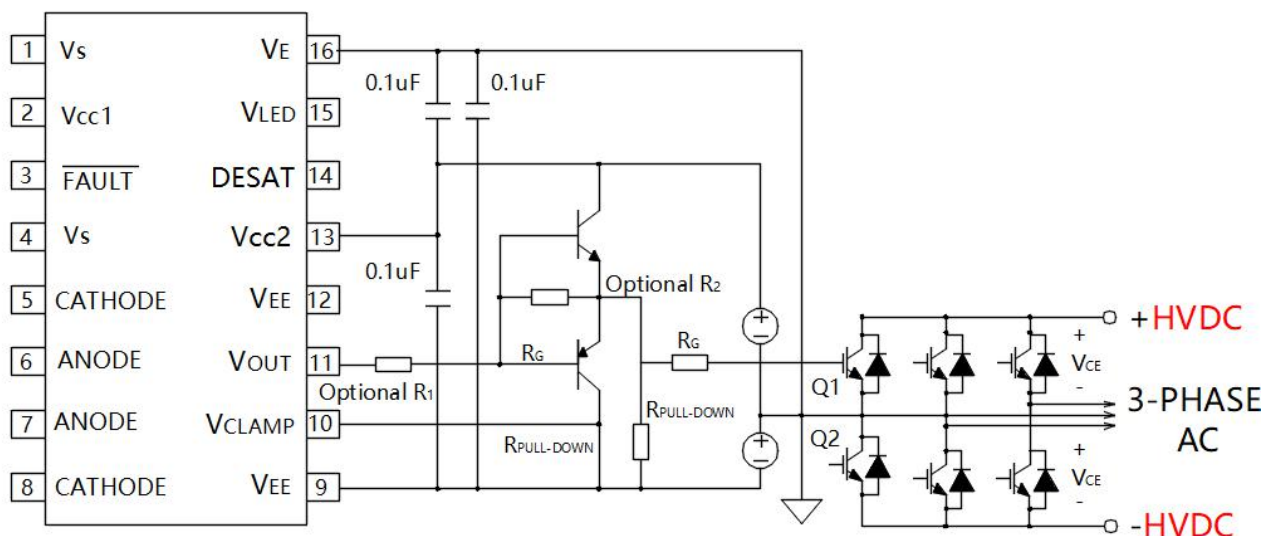
### 4、 Pull-up Resistor on FAULT Pin

The FAULT pin is an open collector output and therefore requires a pull-up resistor to provide a high-level signal. Also the FAULT output can be wire 'OR' ed together with other types of protection (e.g. over-temperature, over- voltage, over-current ) to alert the microcontroller.

### 5、 Other Possible Application Circuit (Output Stage)

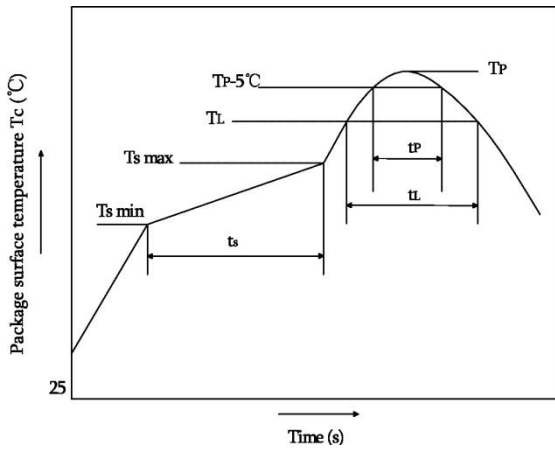
Fig 39. IGBT drive with negative gate drive, external booster and desaturation detection (VClamp should be connected to VEE when it is not used) VClamp is used as secondary gate discharge path. \* indicates component required for negative gate drive topology.

Fig.39





### Reflow soldering

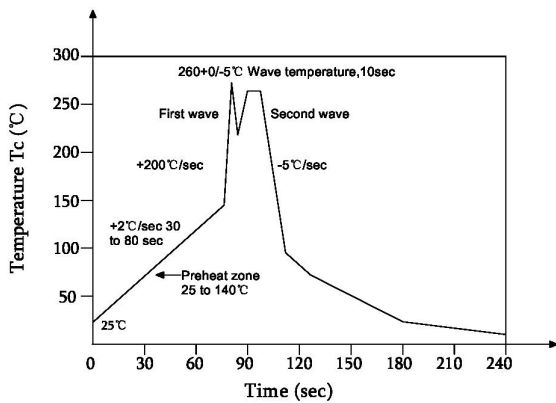


	Symbol	Min	Max	Unit
Preheat temperature	Ts	150	200	°C
Preheat time	ts	60	120	s
Ramp-up rate(TL to Tp)			3	°C/s
Liquidus temperature	TL	217		°C
Time above TL	tL	60	150	s
Peak temperature	Tp		260	°C
Time during which Tc is between (Tp-5) and Tp	tP		30	s
Ramp-down rate(Tp to TL)			6	°C/s

**Note:**

Reflow soldering is recommended at the temperatures and times shown, no more than three times.

### Wave soldering



Profile feature	
Average ramp-up rate	~200°C/s
Heating rate during preheat	1°C/s to 2°C/s typical; 4°C/s maximum
Final preheat temperature Ts	~130°C
Preheat time (25°C to Ts)	>60s
Peak temperature Tp	260°C
Time within peak temperature tp	10s
Ramp-down rate	5°C/s maximum

### Soldering with hand soldering iron

- A. Hand soldering iron is only used for product rework or sample testing.
- B. Hand soldering iron requirements: Temperature: 360 °C+5°C within 3s.

### XL332J

#### Packing

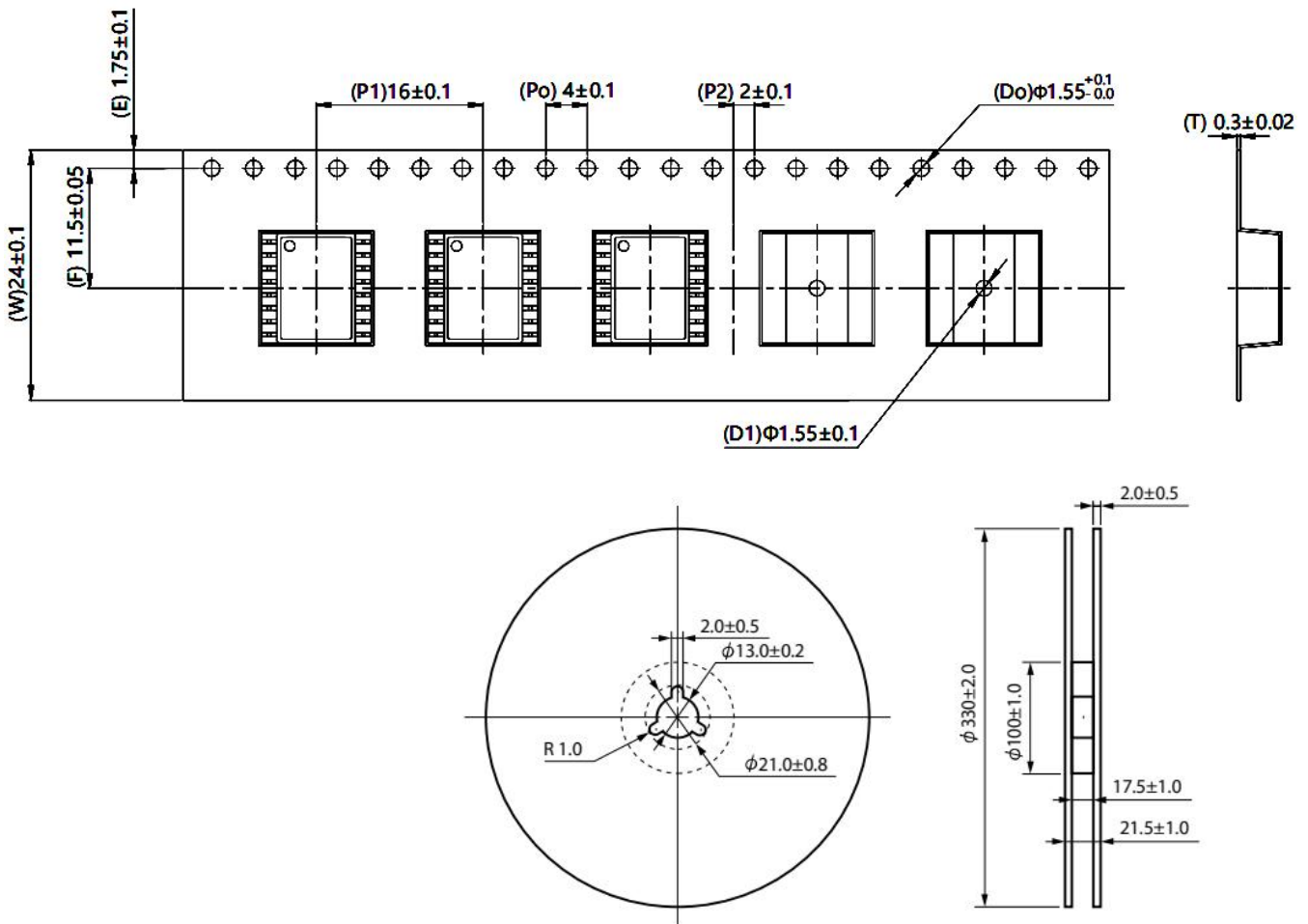
Package Type	Packing Form	Quantity per Tube & Reel	Quantity per Box	Quantity per Carton	Antistatic Bag Specification	Box Specification	Carton Specification	Note
WSOP16	Reel(φ330mm Blue)	1000 pcs/reel	2reels/box	10boxes/ctn	450*390*0.1mm	340*340*75 mm	650*375*365mm	Leave 50 Spaces at the beginning and 100 Spaces at the end

#### ■ WSOP16 (Reel)

Qty/reel: 1000pcs. Qty/box: 2000pcs.

Qty/ctn: 20000pcs.

Schematic: (unit: mm)



#### Attention

**XL332J**

- XINGLIGHT implements dynamic technical updates. Specifications are subject to change. Refer to the official website for the latest version.
- Users must strictly adhere to specified conditions. Failures caused by misuse (overload, high temperature, incompatible circuits) are excluded from warranty.
- Contact technical support for customized validation in critical applications (medical devices, industrial control).
- This document is valid until Dec 31, 2026. Updates will be notified on the official website.
- For further clarification on technical specifications or application solutions, please contact us through official channels.